

March 1993 Revised February 2005

### 74LVX14

## Low Voltage Hex Inverter with Schmitt Trigger Input

### **General Description**

The LVX14 contains six inverter gates each with a Schmitt trigger input. They are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals. In addition, they have a greater noise margin than conventional inverters.

The LVX14 has hysteresis between the positive-going and negative-going input thresholds (typically 1.0V) which is determined internally by transistor ratios and is essentially insensitive to temperature and supply voltage variations.

### **Features**

- Input voltage level translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

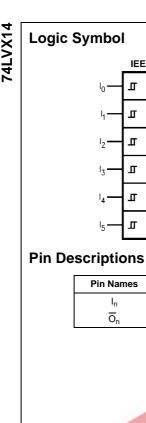


### **Ordering Code:**

	, ,	upply voltage variations.
The inputs tolerate v of 5V systems to 3V		o 7V allowing the interface
Ordering Co	de:	3 3 3
Order Number	Package	Package Description
Order Number	Number	Tackage bescription
74LVX14M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74LVX14MX_NL	M14A	Pb-Free 14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74LVX14SJ	M14D	Pb-Free 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVX14MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74LVX14MTCX_NL (Note 1)	MTC14	Pb-Free 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel, Specify by appending suffix letter "X" to the ordering code Pb-Free package per JEDEC J-STD-020B.

Note 1: "\_NL" indicates Pb-Free package (per JEDEC J-STD-020B). Device available in Tape and Reel only.



# **Connection Diagram**

### **Truth Table**

Cilpuolis		1
Pin Names	Description	Α 4
In	Inputs	200
I <sub>n</sub> O <sub>n</sub>	Outputs	A THE COL
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Input	Output
Α 4	ō
3, W. 114	Н
A H	L

### **Absolute Maximum Ratings**(Note 2)

Supply Voltage ( $V_{CC}$ ) -0.5V to +7.0V

DC Input Diode Current (I<sub>IK</sub>)

DC Output Diode Current (I<sub>OK</sub>)

 $\begin{array}{ll} \mbox{$V_O = -0.5$V$} & -20 \mbox{ mA} \\ \mbox{$V_O = V_{CC} + 0.5$V$} & +20 \mbox{ mA} \end{array}$ 

DC Output Voltage (V  $_{\mbox{\scriptsize O}})$   $-0.5\mbox{\scriptsize V}$  to V  $_{\mbox{\scriptsize CC}}$  + 0.5  $\mbox{\scriptsize V}$ 

DC Output Source

or Sink Current ( $I_O$ )  $\pm 25 \text{ mA}$ 

DC V<sub>CC</sub> or Ground Current

 $(I_{CC} \text{ or } I_{GND})$  ±50 mA

Storage Temperature (T<sub>STG</sub>) -65°C to +150°C
Power Dissipation 180 mW

# Recommended Operating Conditions (Note 3)

Note 2: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

### **DC Electrical Characteristics**

Symbol	Parameter	v <sub>cc</sub>	T <sub>A</sub> = +25°C		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units	Conditions		
	i didilictor		Min	Тур	Max	Min	Max	Office	Conditions	
$V_{t^+}$	Positive Threshold	3.0			2.2	. X	2.2	V		
V <sub>t</sub> -	Negative Threshold	3.0	0.9			0.9	-(1)	V		
V <sub>H</sub>	Hysteresis	3.0	0.3		1.2	0.3	1.2	V		
V <sub>OH</sub>	HIGH Level	2.0	1.9	2.0		1.9			I <sub>OH</sub> = -50 μA	
	Output Voltage	3.0	2.9	3.0		2.9		V	$V_{IN} = V_{IL} \text{ or } V_{IH}   I_{OH} = -50  \mu\text{A}$	
		3.0	2.58	11		2.48			I <sub>OH</sub> = -4 mA	
V <sub>OL</sub>	LOW Level	2.0		0.0	0.1		0.1		$I_{OL} = 50 \mu A$	
	Output Voltage	3.0		0.0	0.1		0.1	V	$V_{IN} = V_{IL} \text{ or } V_{IH}$ $I_{OL} = 50  \mu\text{A}$ $I_{OL} = 4 \text{ mA}$	
		3.0			0.36		0.44		$I_{OL} = 4 \text{ mA}$	
I <sub>IN</sub>	Input Leakage Current	3.6			±0.1		±1.0	μА	V <sub>IN</sub> = 5.5V or GND	
Icc	Quiescent Supply Current	3.6			2.0		20	μА	$V_{IN} = V_{CC}$ or GND	

### Noise Characteristics (Note 4)

Symbol	Parameter	V <sub>CC</sub>	CC T <sub>A</sub> = 25°C		Units	C <sub>L</sub> (pF)	
	T didiliotoi	(V)	Тур	Limit	•		
V <sub>OLP</sub>	Quiet Output Maximum Dynamic V <sub>OL</sub>	3.3	0.3	0.5	V	50	
V <sub>OLV</sub>	Quiet Output Minimum Dynamic V <sub>OL</sub>	3.3	-0.3	-0.5	V	50	
V <sub>IHD</sub>	Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	50	
V <sub>ILD</sub>	Maximum LOW Level Dynamic Input Voltage	3.3		0.8	V	50	

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Note 4: Input  $t_r = t_f = 3ns$ 

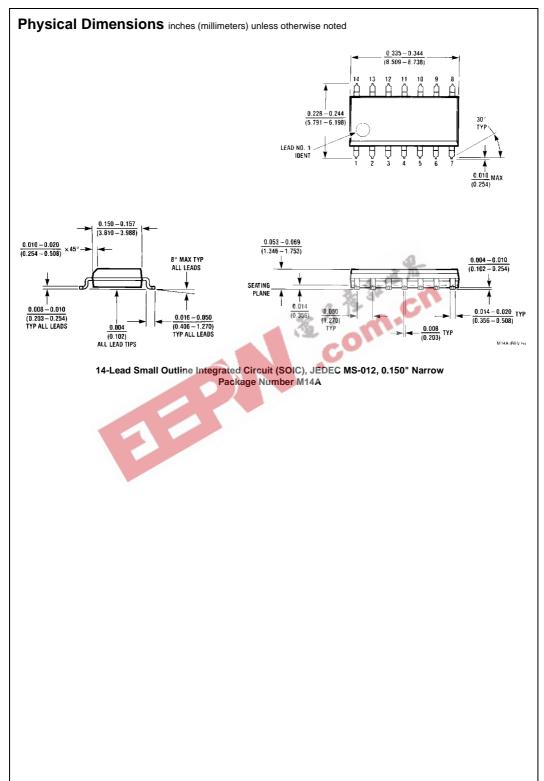
Symbol		V <sub>CC</sub>	$T_A = +25^{\circ}C$		$T_A = -40^{\circ}C$ to $+85^{\circ}C$		Units	C <sub>L</sub> (pF)	
	Parameter	(V)	Min	Тур	Max	Min	Max	Onnes	S[ (pi )
t <sub>PLH</sub>	Propagation	2.7		8.7	16.3	1.0	19.5		15
t <sub>PHL</sub>	Delay Time	2.7		11.2	19.8	1.0	23.0	no	50
		3.3 ± 0.3		6.8	10.6	1.0	12.5	ns	15
		3.3 ± 0.3		9.3	14.1	1.0	16.0		50

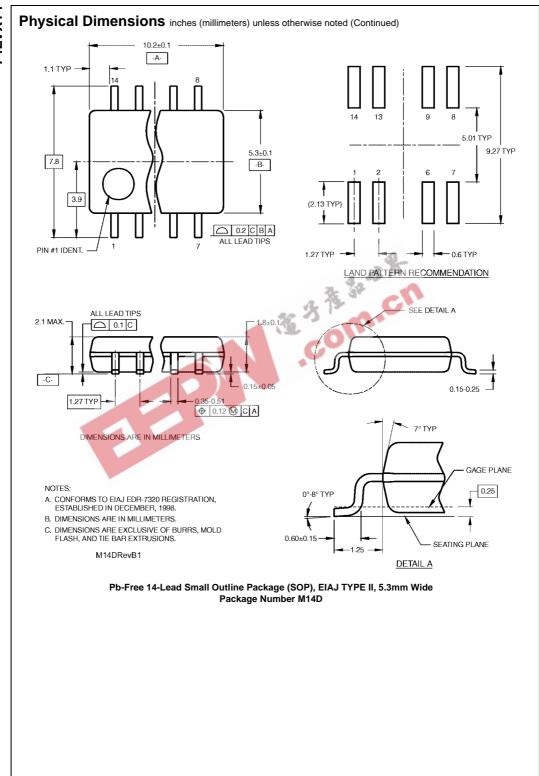
Note 5: Parameter guaranteed by design.  $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$ ,  $t_{OSHL} = |t_{PHLm} - t_{PHLn}|$ 

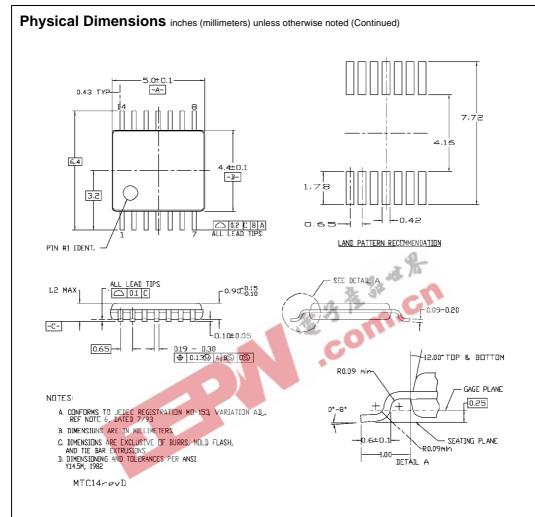
### Capacitance

Symbol	Parameter		T <sub>A</sub> = +25°0	;	T <sub>A</sub> = -40°	Units	
Symbol	Faranteter	Min	Тур	Max	Min	Max	Ullits
C <sub>IN</sub>	Input Capacitance		4	10		10	pF
C <sub>PD</sub>	Power Dissipation		21				pF
	Capacitance (Note 6)		21	-0			ρı
	Average operating current can be obtained by the equ	ation: Iccor		V <sub>CC</sub> × f <sub>IN</sub> 6 (per Gate)			









14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package Number MTC14

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